

阅读申明

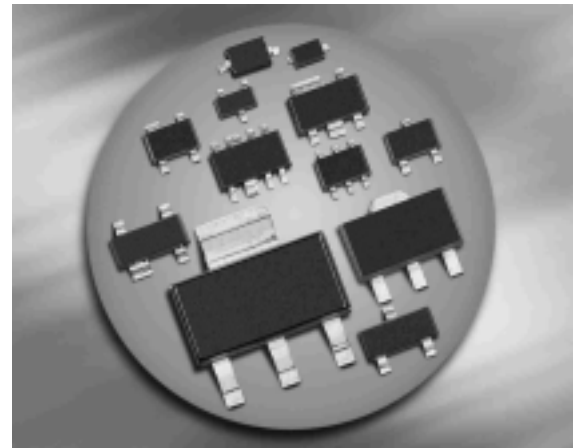
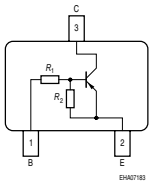
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PNP Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=2.2\text{ k}\Omega$, $R_2=47\text{ k}\Omega$)


**BCR158/F/L3
BCR158T/W**


Type	Marking	Pin Configuration						Package
		1=B	2=E	3=C	-	-	-	
BCR158	WIs	1=B	2=E	3=C	-	-	-	SOT23
BCR158L3	WI	1=B	2=E	3=C	-	-	-	TSFP-3
BCR158F	WIs	1=B	2=E	3=C	-	-	-	TSLP-3-4
BCR158T	WI	1=B	2=E	3=C	-	-	-	SC75
BCR158W	WIs	1=B	2=E	3=C	-	-	-	SOT323

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Input forward voltage	$V_{i(fwd)}$	20	
Input reverse voltage	$V_{i(rev)}$	5	
Collector current	I_C	100	mA
Total power dissipation- BCR158, $T_S \leq 102^\circ\text{C}$ BCR158F, $T_S \leq 128^\circ\text{C}$ BCR158L3, $T_S \leq 135^\circ\text{C}$ BCR158T, $T_S \leq 109^\circ\text{C}$ BCR158W, $T_S \leq 124^\circ\text{C}$	P_{tot}	200 250 250 250 250	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}		K/W
BCR158		≤ 240	
BCR158F		≤ 90	
BCR158L3		≤ 60	
BCR158T		≤ 165	
BCR158W		≤ 105	

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

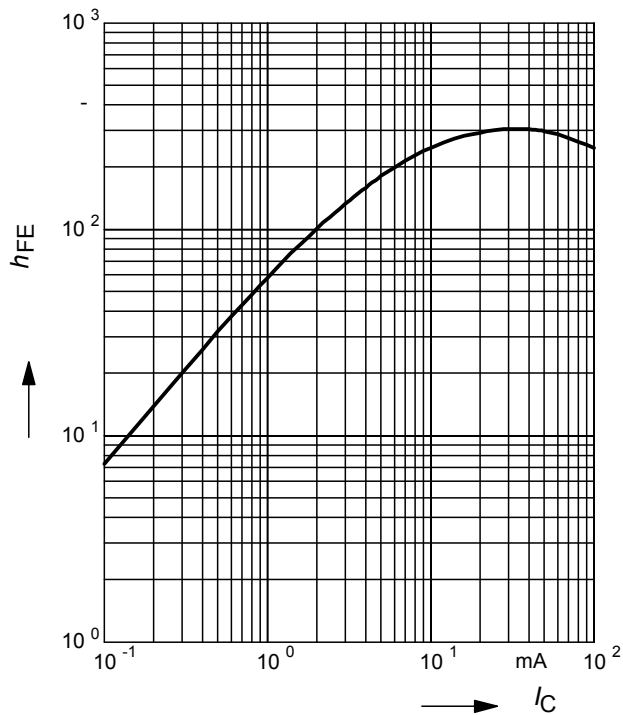
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(BR)CBO}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 5 \text{ V}, I_C = 0$	I_{EBO}	-	-	164	μA
DC current gain ¹⁾ $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	h_{FE}	70	-	-	-
Collector-emitter saturation voltage ¹⁾ $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$	V_{CEsat}	-	-	0.3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$	$V_{i(off)}$	0.4	-	0.8	
Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$	$V_{i(on)}$	0.5	-	1.1	
Input resistor	R_1	1.5	2.2	2.9	$\text{k}\Omega$
Resistor ratio	R_1/R_2	0.042	0.047	0.052	-
AC Characteristics					
Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	f_T	-	200	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{cb}	-	3	-	pF

¹Pulse test: $t < 300 \mu\text{s}$; $D < 2\%$

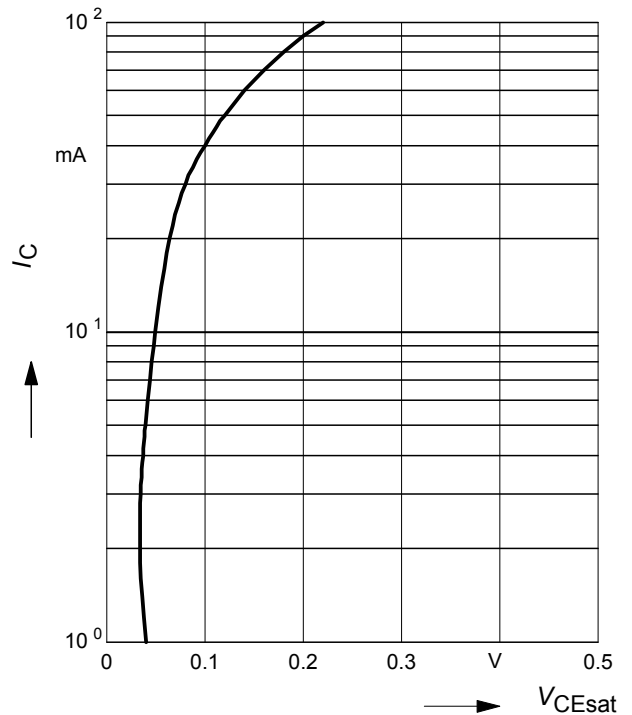
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



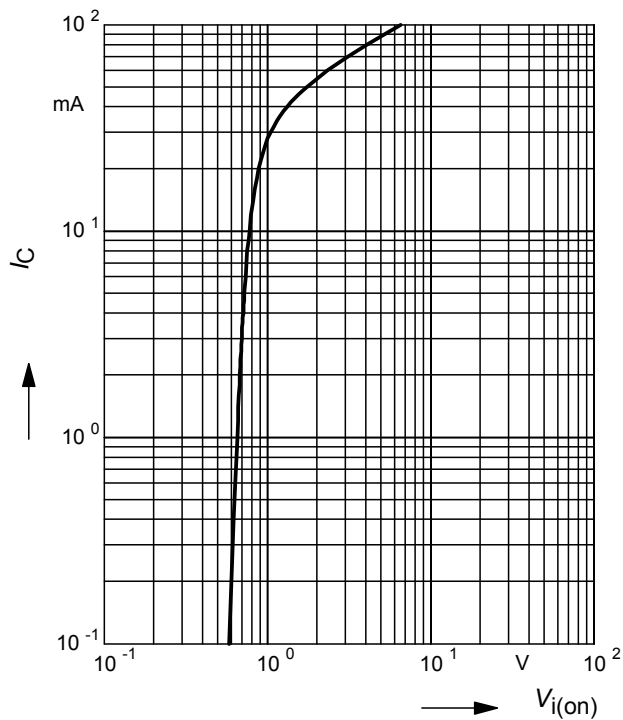
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C), h_{FE} = 20$



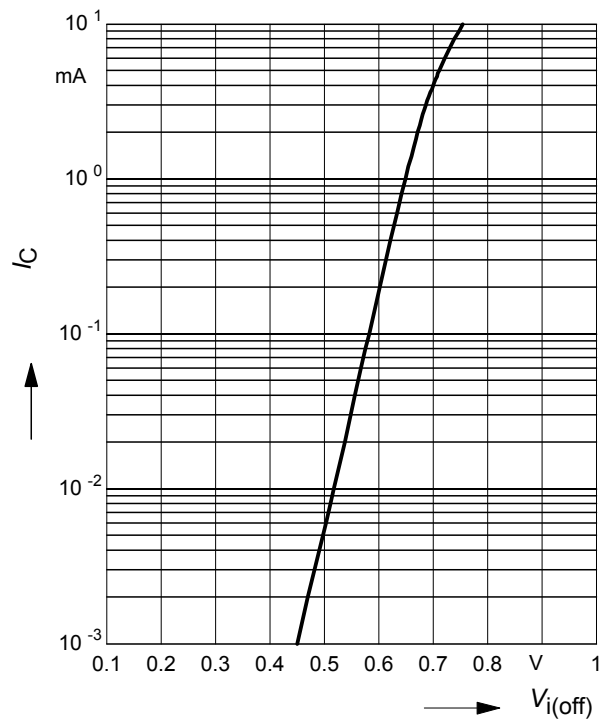
Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3V$ (common emitter configuration)



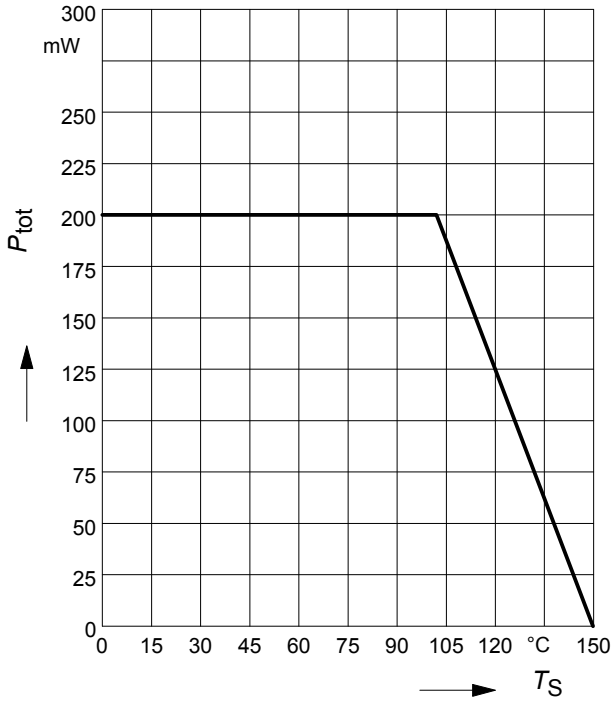
Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



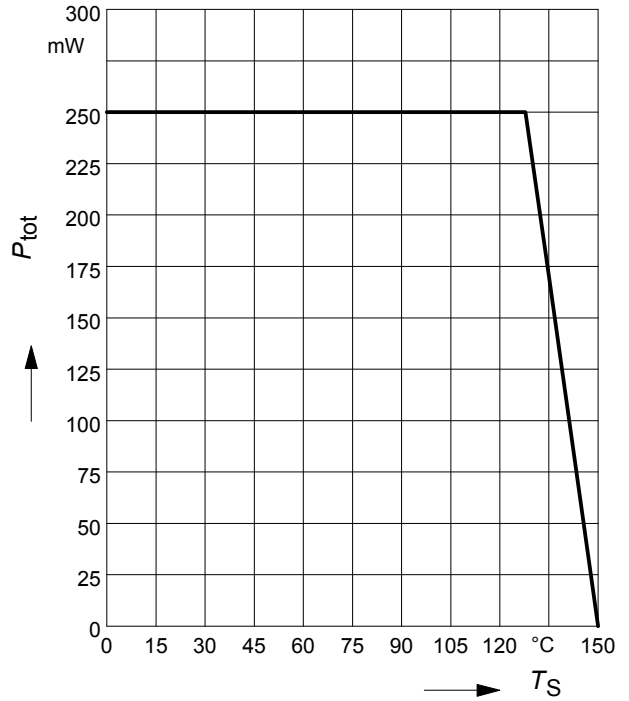
Total power dissipation $P_{tot} = f(T_S)$

BCR158



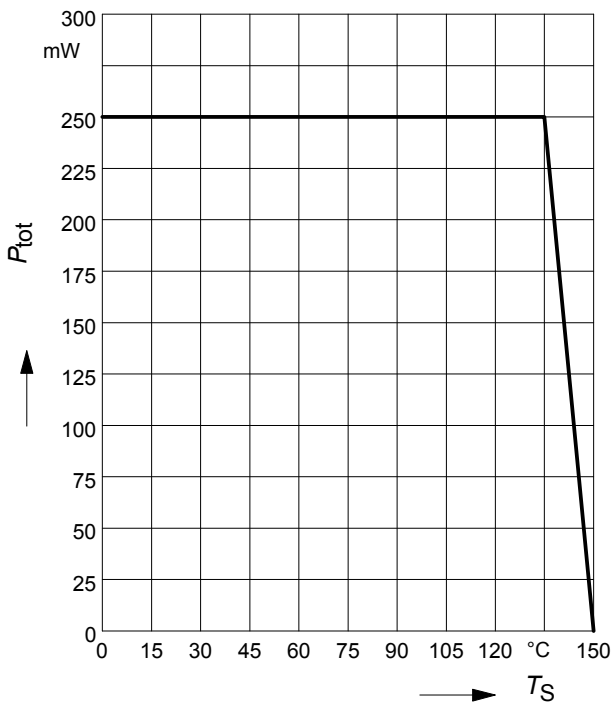
Total power dissipation $P_{tot} = f(T_S)$

BCR158F



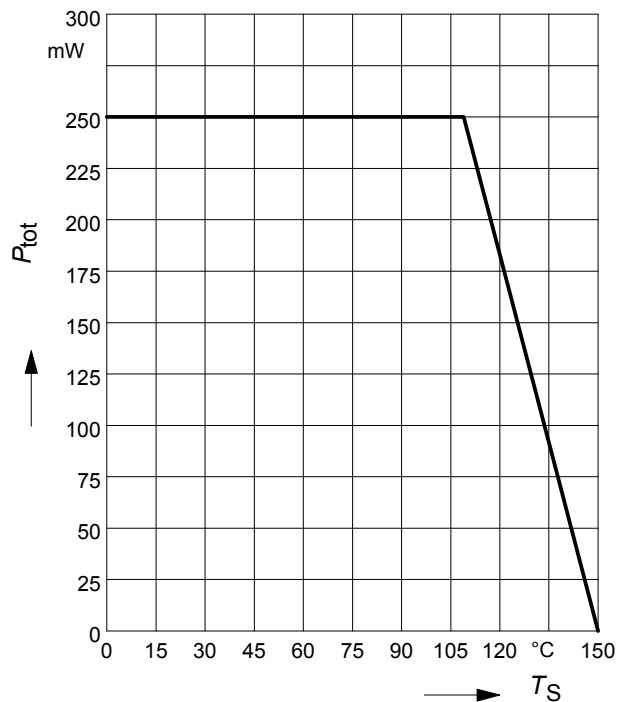
Total power dissipation $P_{tot} = f(T_S)$

BCR158L3



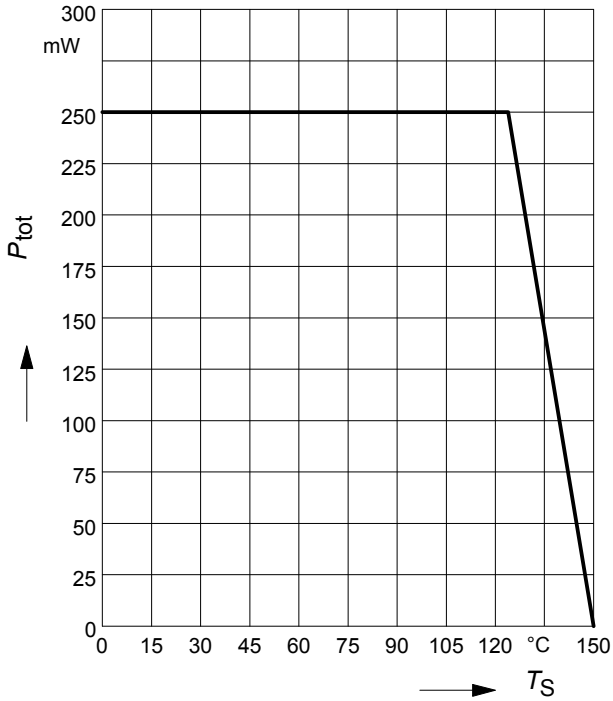
Total power dissipation $P_{tot} = f(T_S)$

BCR158T



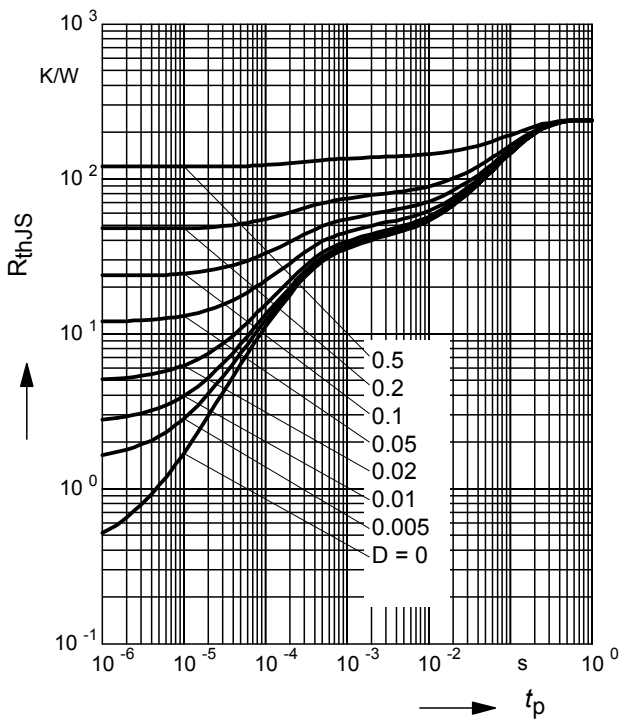
Total power dissipation $P_{tot} = f(T_S)$

BCR158W



Permissible Pulse Load $R_{thJS} = f(t_p)$

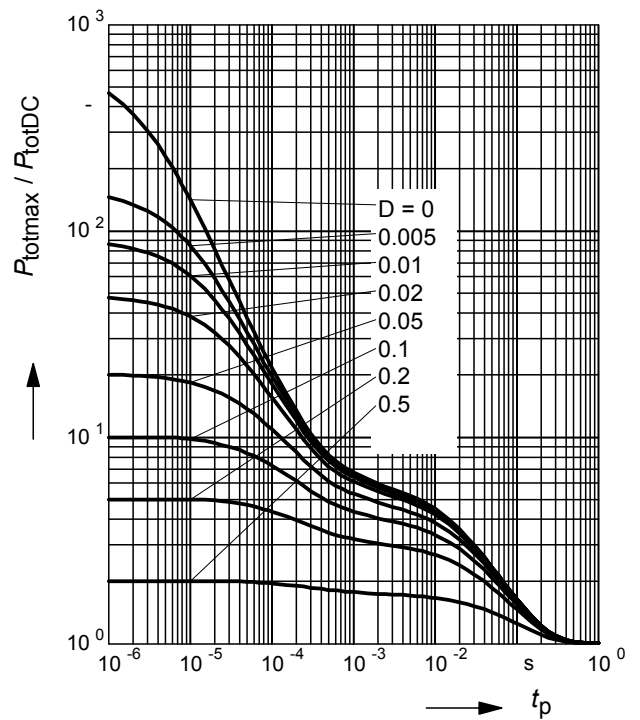
BCR158



Permissible Pulse Load

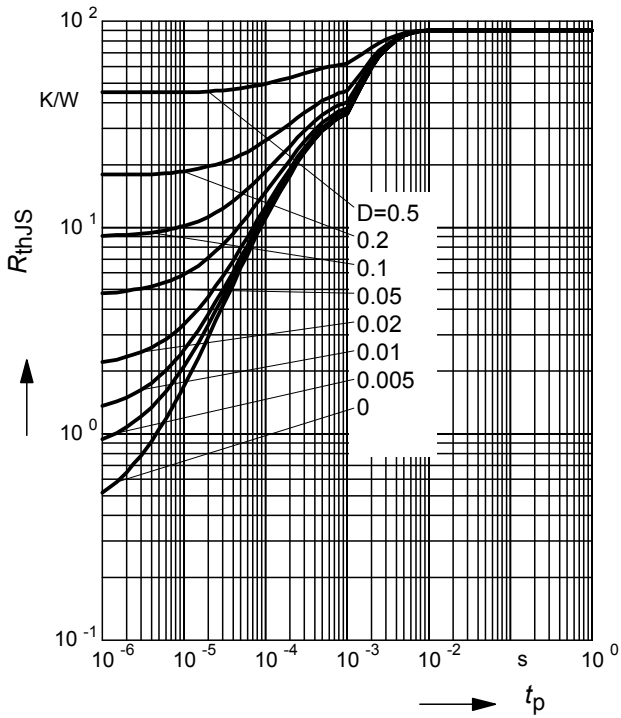
$P_{totmax}/P_{totDC} = f(t_p)$

BCR158



Permissible Puls Load $R_{thJS} = f(t_p)$

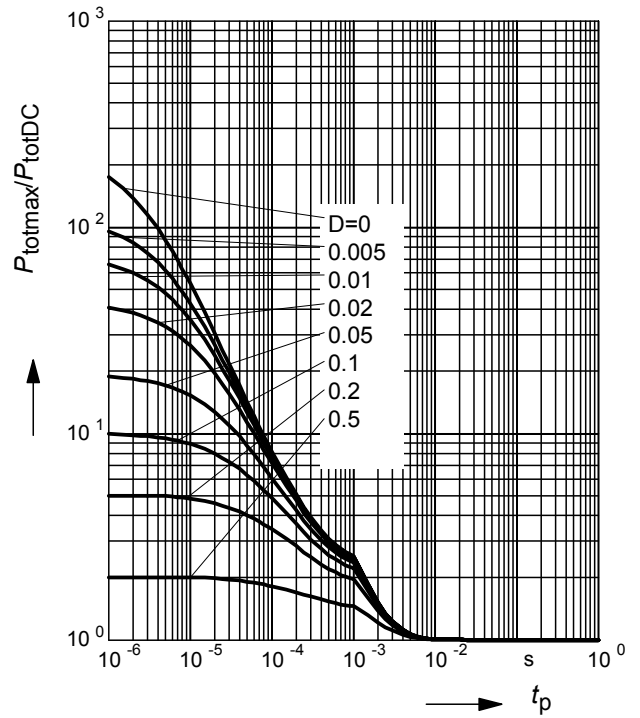
BCR158F



Permissible Pulse Load

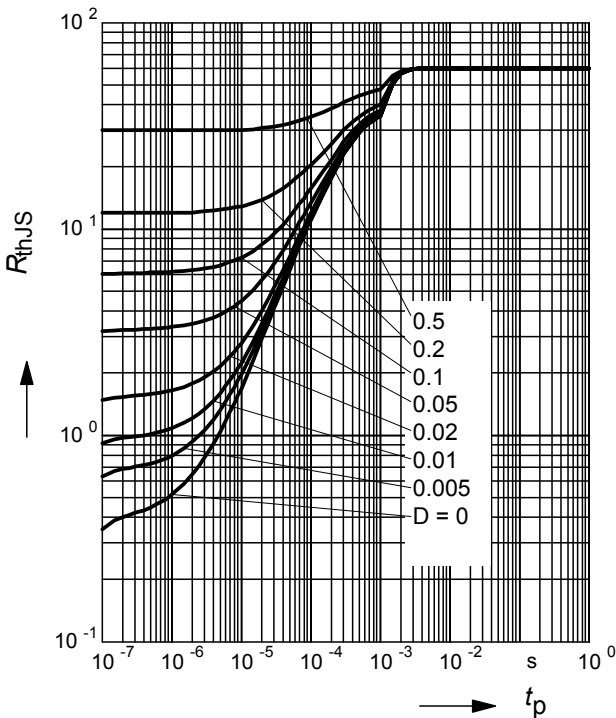
$P_{totmax}/P_{totDC} = f(t_p)$

BCR158F



Permissible Puls Load $R_{thJS} = f(t_p)$

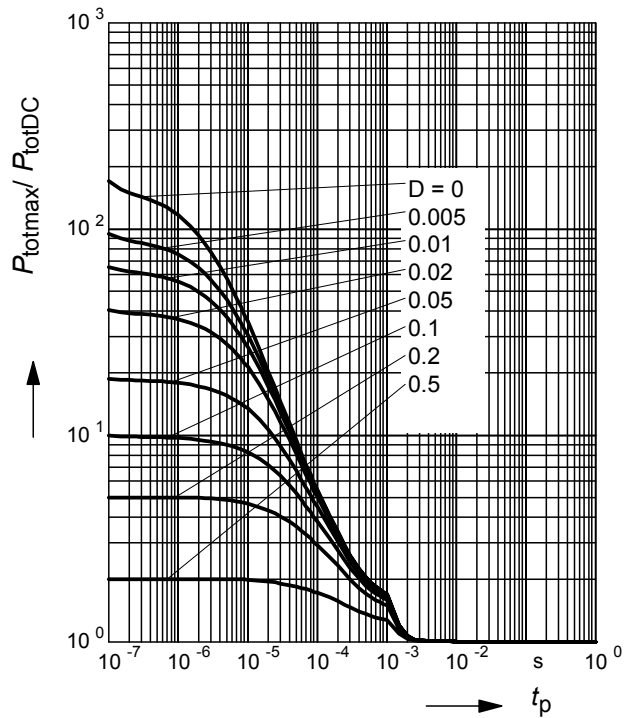
BCR158L3



Permissible Pulse Load

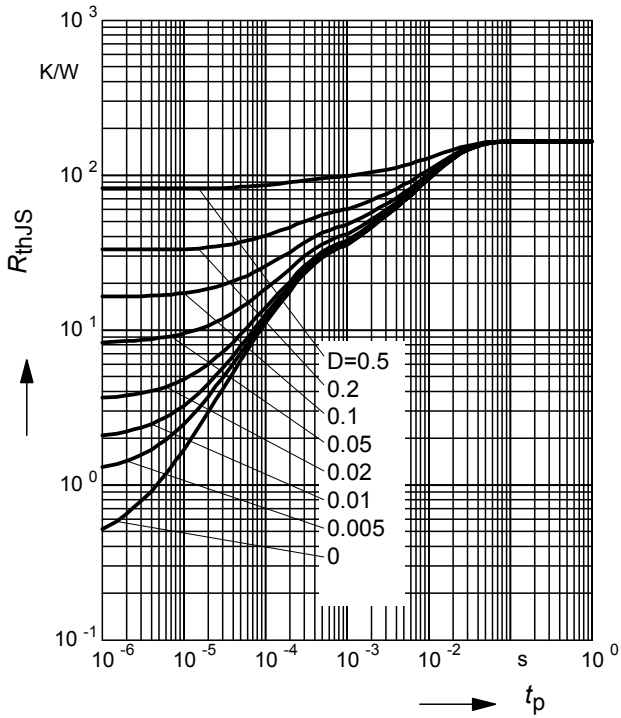
$P_{totmax}/P_{totDC} = f(t_p)$

BCR158L3



Permissible Puls Load $R_{thJS} = f(t_p)$

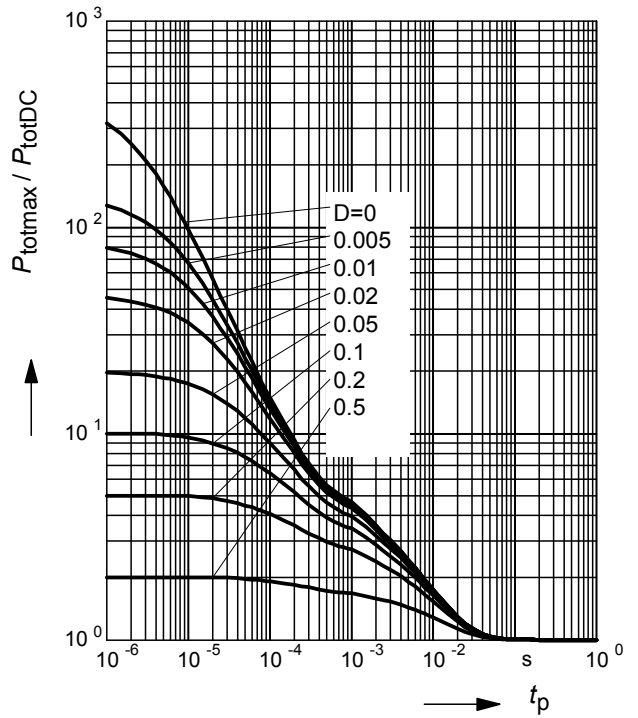
BCR158T



Permissible Pulse Load

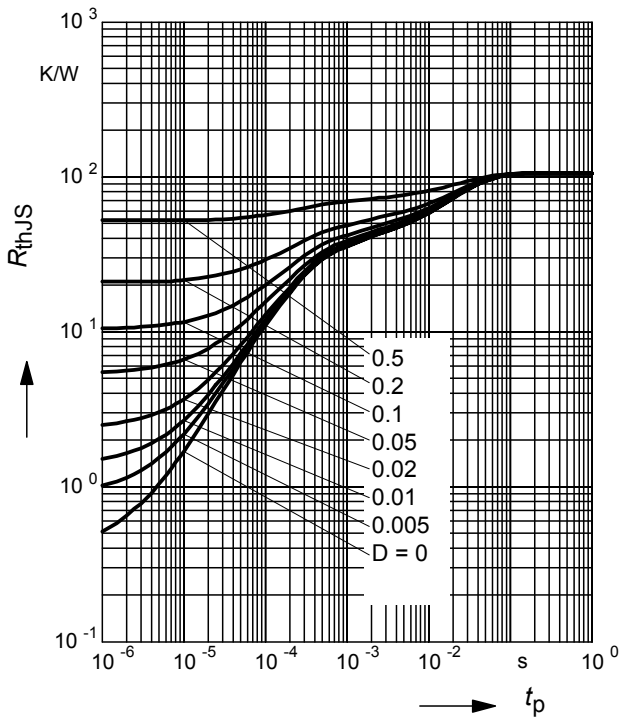
$P_{totmax}/P_{totDC} = f(t_p)$

BCR158T



Permissible Puls Load $R_{thJS} = f(t_p)$

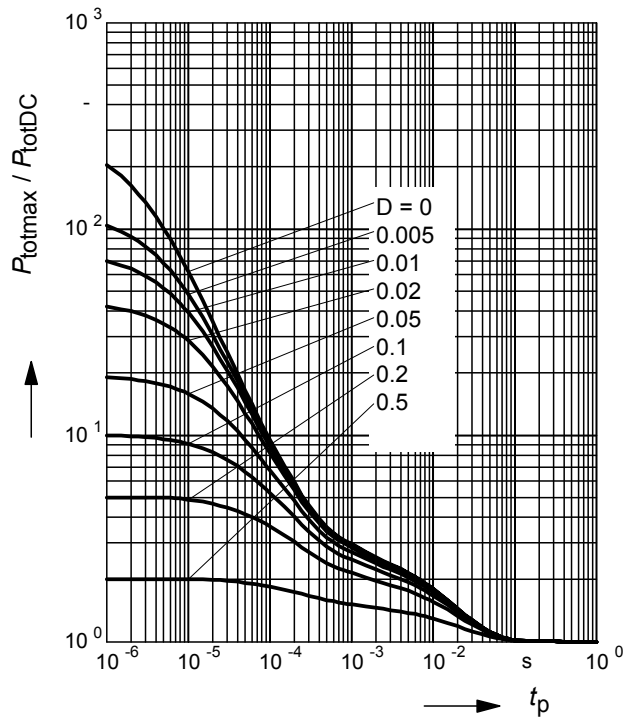
BCR158W



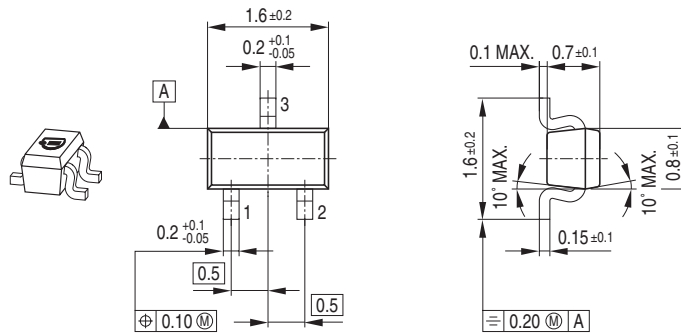
Permissible Pulse Load

$P_{totmax}/P_{totDC} = f(t_p)$

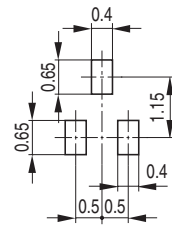
BCR158W



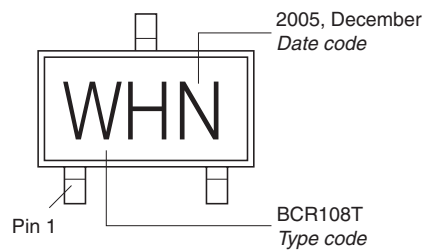
Package Outline



Foot Print

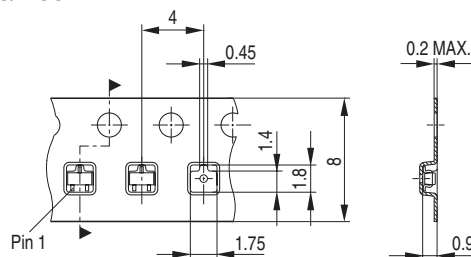


Marking Layout (Example)



Standard Packing

Reel $\phi 180 \text{ mm} = 3.000 \text{ Pieces/Reel}$
 Reel $\phi 330 \text{ mm} = 10.000 \text{ Pieces/Reel}$

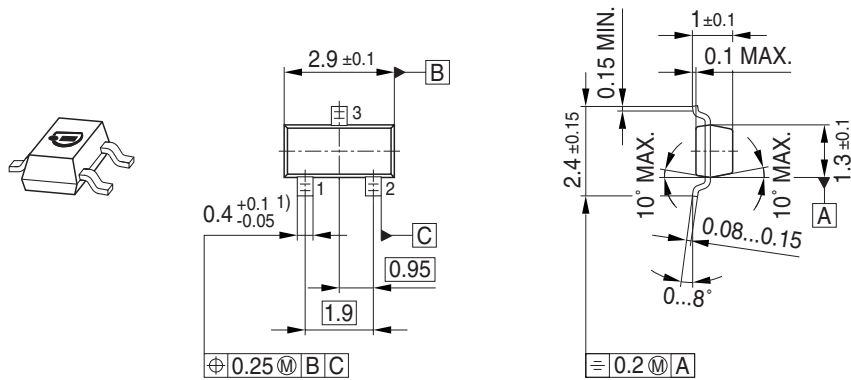


Date Code marking for discrete packages with one digit (SCD80, SC79, SC75¹⁾) CES-Code

Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	a	p	A	P	a	p	A	P	a	p	A	P
02	b	q	B	Q	b	q	B	Q	b	q	B	Q
03	c	r	C	R	c	r	C	R	c	r	C	R
04	d	s	D	S	d	s	D	S	d	s	D	S
05	e	t	E	T	e	t	E	T	e	t	E	T
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	v	G	V	g	v	G	V	g	v	G	V
08	h	x	H	X	h	x	H	X	h	x	H	X
09	j	y	J	Y	j	y	J	Y	j	y	J	Y
10	k	z	K	Z	k	z	K	Z	k	z	K	Z
11	l	2	L	4	l	2	L	4	l	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

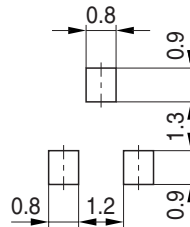
1) New Marking Layout for SC75, implemented at October 2005.

Package Outline

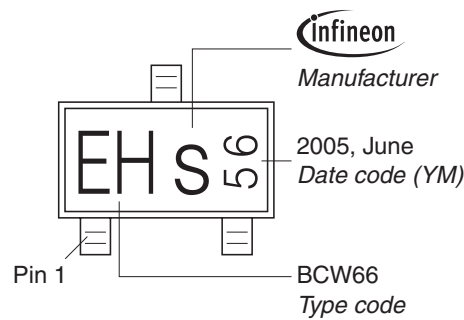


1) Lead width can be 0.6 max. in dambar area

Foot Print

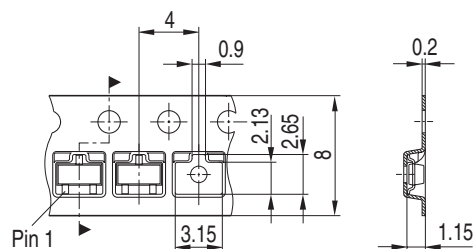


Marking Layout (Example)

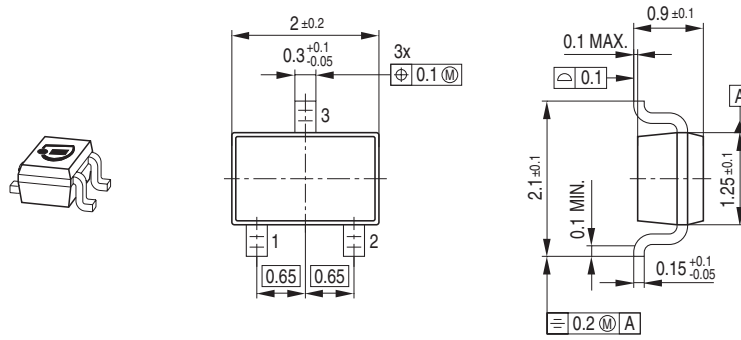


Standard Packing

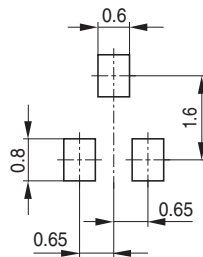
Reel \varnothing 180 mm = 3.000 Pieces/Reel
 Reel \varnothing 330 mm = 10.000 Pieces/Reel



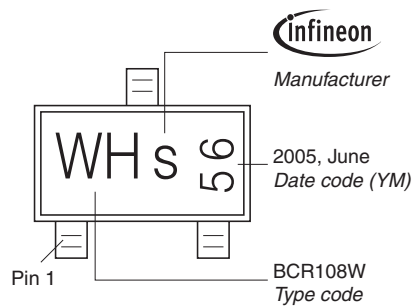
Package Outline



Foot Print

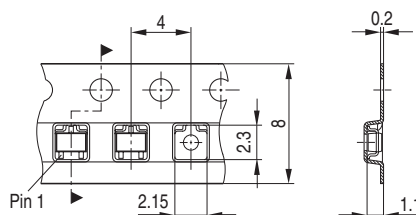


Marking Layout (Example)

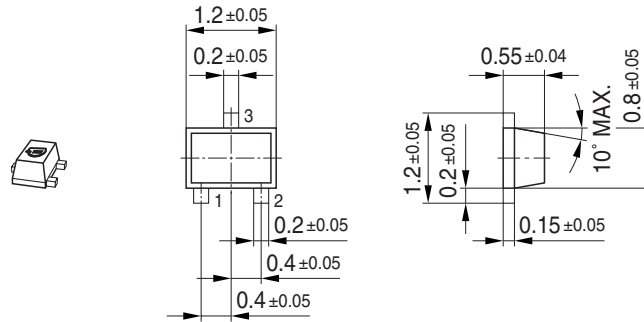


Standard Packing

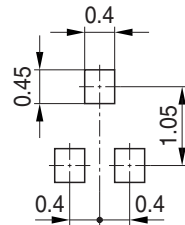
Reel \varnothing 180 mm = 3.000 Pieces/Reel
 Reel \varnothing 330 mm = 10.000 Pieces/Reel



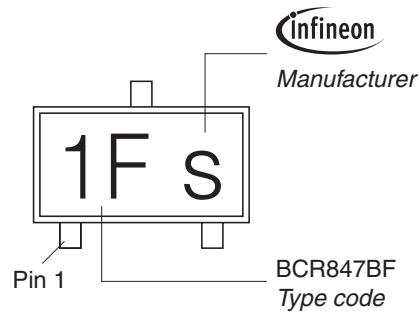
Package Outline



Foot Print

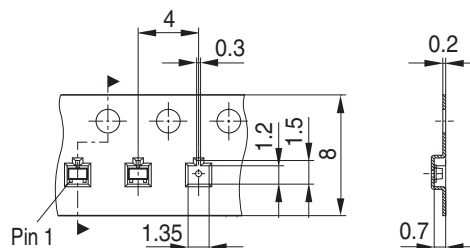


Marking Layout (Example)

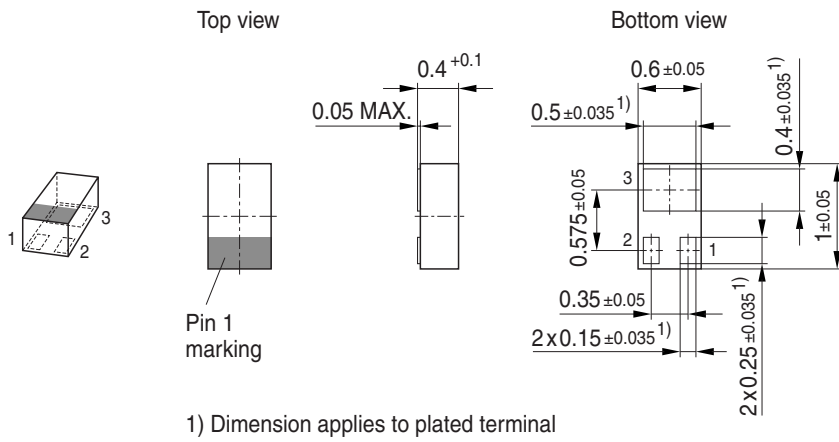


Standard Packing

Reel \varnothing 180 mm = 3.000 Pieces/Reel
 Reel \varnothing 330 mm = 10.000 Pieces/Reel

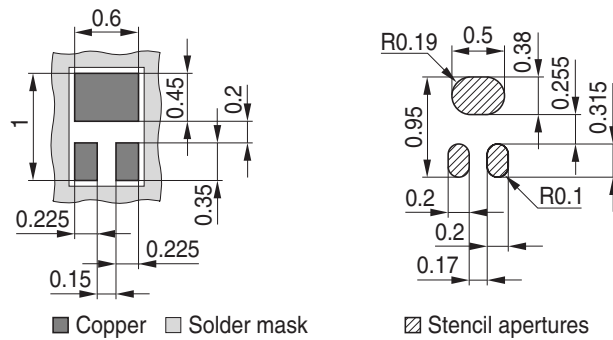


Package Outline

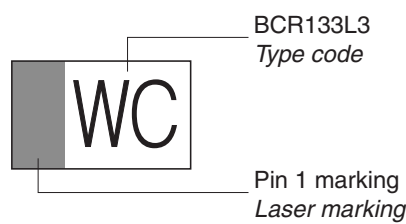


Foot Print

For board assembly information please refer to Infineon website "Packages"

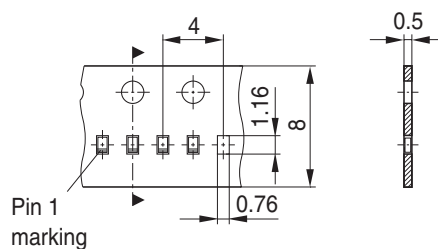


Marking Layout



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel



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